

## Thyristor-Diode Module, 50 Amps

**Features**

- Improved glass passivation for high reliability
- Exceptional stability at high temperatures
- High di/dt and dv/dt capabilities
- Low thermal resistance

**Voltage Ratings** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

Type number	Voltage Code	$V_{RRM}$ , Maximum repetitive peak reverse voltage (V)	$V_{RSM}$ , Maximum non-repetitive peak reverse voltage (V)	$V_{DRM}$ , Maximum repetitive peak off-state voltage (V)	$I_{RRM}$ , Maximum reverse leakage current @ $T_{JMAX}$ (mA)
NTD57 H	200	2000	2100	2000	max. 30
	220	2200	2300	2200	

**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

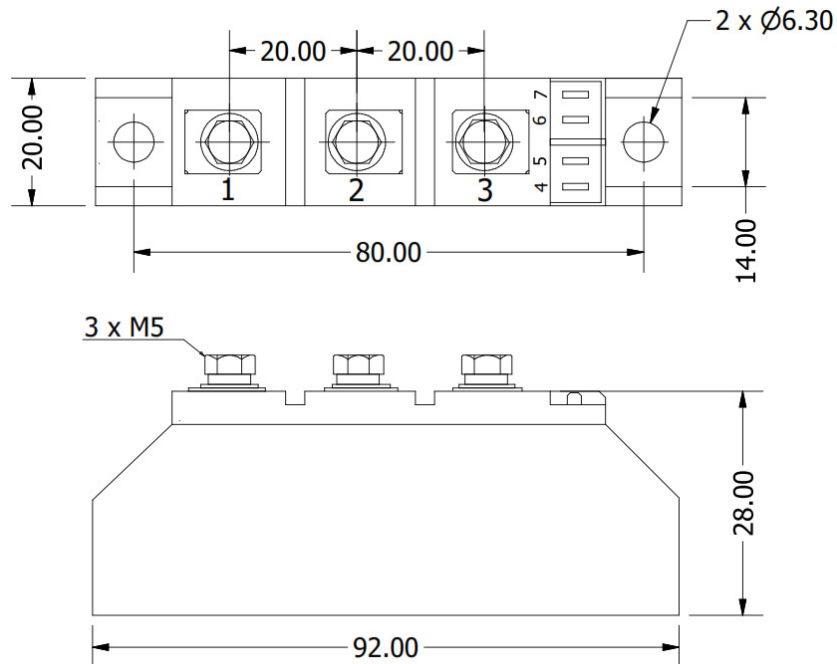
Parameter	Symbol	Values	Units
Maximum average forward current @ $T_J = 85^\circ\text{C}$	$I_{T(AV)}$	50	A
Maximum average RMS forward current	$I_{T(RMS)}$	79	A
Maximum non-repetitive surge current	$I_{TSM}$	1500	A
Maximum $I^2t$ for fusing	$I^2t$	11250	$\text{A}^2\text{s}$
Forward voltage drop	$V_{TM}$	max. 1.6	V
Critical rate of rise of on-state current	di/dt	max. 150	$\text{A}/\mu\text{s}$
Critical rate of rise of off-state voltage	dv/dt	max. 1000	$\text{V}/\mu\text{s}$
Gate current required to trigger	$I_{GT}$	min. 150	mA
Gate voltage required to trigger	$V_{GT}$	min. 3	V
Maximum holding current	$I_H$	150	mA
Maximum latching current	$I_L$	300	mA
Isolation voltage	$V_{ISO}$	4000	V

**Thermal & Mechanical Specifications** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Values	Units
Operating junction temperature range	$T_J$	-40 to +125	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-40 to +125	$^\circ\text{C}$
Thermal resistance, junction to case	$R_{th(JC)}$	0.57	$^\circ\text{C}/\text{W}$
Mounting torque	F	to heatsink	$5 \pm 15\%$
		to terminals	$3 \pm 15\%$
Weight	W	100	g

## Package Outline

(All dimensions in mm)



## Circuit Configuration

Circuit Description	Configuration Code	Circuit Drawing
Series Connection (doubler circuit)	N	<p>The circuit diagram shows two diodes connected in series. The first diode has its anode connected to terminal 1 and its cathode to terminal 2. The second diode has its anode connected to terminal 2 and its cathode to terminal 3. Terminal 4 is connected to ground (G), and terminal 5 is connected to the cathode of the second diode. Terminal 6 is connected to the anode of the first diode, and terminal 7 is connected to the cathode of the second diode.</p>
Common Anode	A	<p>The circuit diagram shows two diodes connected in a common anode configuration. The anodes of both diodes are connected to terminal 2. The cathode of the first diode is connected to terminal 1, and the cathode of the second diode is connected to terminal 3. Terminal 4 is connected to ground (G), and terminal 5 is connected to the cathode of the second diode. Terminal 6 is connected to the anode of the first diode, and terminal 7 is connected to the cathode of the second diode.</p>



## Ordering Table

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<i>NTT</i>	<i>57</i>	<i>N</i>	<i>200</i>	<i>H</i>
1	2	3	4	5

1 – Power Module

- > DD = Diode-Diode
- > TD = Thyristor-Diode
- > TT = Thyristor-Thyristor

2 – Current Rating =  $I_{T(AV)}$

3 – Circuit Configuration (see Table)

4 – Voltage Code (see Voltage Ratings table)

5 – High Voltage (2000V, 2200V)